

# Contact Current Distortion Due to Tunnel Effect

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## Abstract

The third harmonic distortion ratio of the tunnel current between two electrodes separated by a thin insulating film, is evaluated analyzing the formula derived by Simmons into the Fourier series in this paper. The results show that the theoretical third harmonic distortion ratio is a function of  $s\phi_o^{1/2}$  (where  $s$  is the thickness of the film, and  $\phi_o$  is the work function). The numerical evaluation results in  $-40$  to  $-80$  dB, when  $s$  is in the practical range of  $0.4 \sim 2.0$  nm and  $\phi_o$  is  $1 \sim 4$  eV. Experimental results produce readings of  $-50$  to  $-130$  dB, when using practical contact materials (95Au-5Ni). The reasons for the discrepancy may involve the effect of the non-homogeneous contact area, which was observed using a scanning tunneling microscope. When the contact resistance of copper with a thin insulating film is measured, the resultant small and negative thermal coefficient of contact resistance proves that tunnel resistance does exist. It is also shown that this tunnel film, a contact deterioration caused by corrosion, can be detected using harmonic measurement.

*Key words: Contact current, contact resistance, Fourier expansion, insulating film, third harmonic, tunnel effect.*